TOSHIBA PHOTOCOUPLER GaAs IRED & PHOTO-TRANSISTOR

TLP627,TLP627-2,TLP627-4

PROGRAMMABLE CONTROLLERS **DC-OUTPUT MODULE TELECOMMUNICATION**

The TOSHIBA TLP627,-2 and -4 consists of a gallium arsenide infrared emitting diode optically coupled to a darlington connected phototransistor which has an integral base-emitter resistor to optimize switching speed and elevated temperature characteristics.

The TLP627-2 offers two isolated channels in a eight lead plastic DIP, while the TLP627-4 provide four isolated channels per package.

MADE IN JAPAN

E67349

7426, 7427

Collector-Emitter Voltage

UL Recognized

BSI Approved

- **Current Transfer Ratio**
- **Isolation Voltage UL** Recognized

*1 UL1577

: 1000%(Min) : 5000Vrms(Min)

*1

*2

: 300V(Min)

: UL1577, File No.E67349

E152349

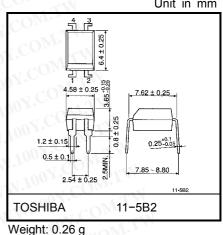
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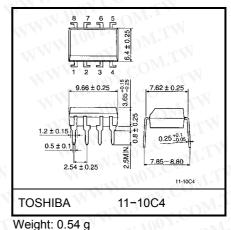
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*1

*2

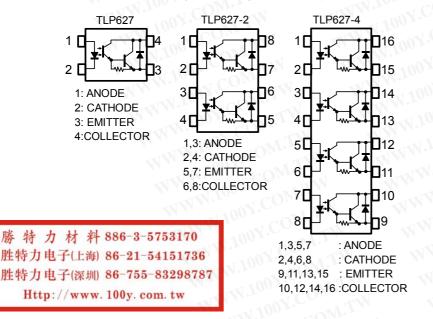


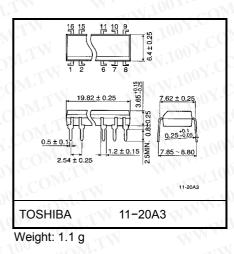




PIN CONFIGURATION (TOP VIEW)

*2 BS EN60065 : 1994,BS EN60950: 1992





MAXIMUM RATINGS(Ta=25°C)

	MANNI 1002 CONTRACT MANNI	1100%.	RAT	ΓING	
Y	CHARACTERISTIC	SYMBOL	TLP627	TLP627-2 TLP627-4	- UNI
	Forward Current	IF	60	50	mA
1.1	Forward Current Derating	∆l _F /°C	−0.7(Ta≥39°C)	−0.5(Ta≥25°C)	mA /
1.	Pulse Forward Current	I _{FP}	1(100µs pu	ilse,100pps)	Α
LED	Power Dissipation (1 Circuit)	PD	100	70	mW
) N.	Power Dissipation Derating (Ta≥25°C,1 Circuit)	$\Delta P_D /°C$	-1.0	-0.7	mW /
0	Reverse Voltage	VR	100Y.CO	5	V
CC	Junction Temperature	Тj	N.C.	25	°C
	Collector-Emitter Voltage	V _{CEO}	3	00	V
٩	Emitter -Collector Voltage	V _{ECO}	NN.1000X.0	.3	V
ECTOR	Collector Current	lc	1	50	mA
Ш	Collector Power Dissipation (1 Circuit)	Pc	150(*300)	100	mW
ō	Collector Power Dissipation Derating (Ta≥25°C,1 Circuit)	Δ P _c /°C	-1.5(*-3.5)	-1.0	mW /°
	Junction Temperature	Tj	1	25	°C
Ope	erating Temperature Range	T _{opr}	-55	~100	°C
Sto	rage Temperature Range	T _{stg}	-55	~125	°C
Lea	d Soldering Temperature (10s)	T _{sold}	260(1	10sec)	°C
Tot	al Package Power Dissipation	PT	250(*320)	150	mW
Tot	al Package Power Dissipation Derating (Ta≥25°C,1 Circuit)	$\Delta P_T / C$	-2.5(*-3.2)	-1.5	mW /
Isol	ation Voltage (AC,1min. , R.H.≤60%) (Note1)	BVs	50	000	Vrm

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V _{cc}	<u> N</u>		200	V
Forward Current	T F	-1	16	25	mA
Collector Current	lc		1 The second	120	mA
Operating Temperature	T _{opr}	-25	N P IN	85	0°

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INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta=25°C)

N	N 10	0.	1.1. 1. 1001.				
	Forward Voltage	VF	I _F = 10 mA	1.0	1.15	1.3	
ĒD	Reverse Current	IR	V _R = 5 V	N.COM	1tm	10	
	Capacitance	Ст	V = 0 , f=1MHz	N.CON	30	_	
1	Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	IC = 0.1mA	300	T	- N	
TECTOR	Emitter-Collector Breakdown Voltage	V _{(BR)ECO}	IE = 0.1mA	0.3	011.1	<u> </u>	
	Collector Dark Current	1001	V _{CE} = 200V	N.100X.	10	200	
DET	Collector Dark Current	I _{CEO}	V _{CE} = 200V , Ta = 85°C	1001		20	
	Capacitance Collector to Emitter	C _{CE}	V=0 , f=1MHz	NN.100	10	MT.W	

WWW.100Y.COM.TV COUPLED ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Current Transfer Ratio	I _C /I _F	I _F =1mA , V _{CE} =1V	1000	4000		%
Saturated CTR	I _C /I _F (sat)	I _F =10mA , V _{CE} =1V	500	N	07.0	%
Collector-Emitter	V (oot)	I _C =10mA , I _F =1mA	-14	<u> </u>	1.0	V
Saturation Voltage	V _{CE} (sat)	I _C =100mA , I _F =10mA	0.3 <	W.	1.2	CV

100X.COM.TW 100X.COM.TW ISOLATION ELECTRICAL CHARACTERISTICS (Ta=25°C)

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CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Capacitance Input to Output	Cs	V _S =0 , f=1MHz	NT N	0.8	VI II V	pF
Isolation Resistance	Rs	V _s =500V , R.H.≤60%	5×10 ¹⁰	10 ¹⁴	K	Ω
W . 1001.C	MUT	AC, 1minute	5000	_		Vrms
Isolation Voltage	BVs	AC, 1second, in oil	-ONFUL	10000	<u>N</u> Y	- 11115
	WTN	DC, 1 minute, in oil	T.tr	10000	_//	Vdc

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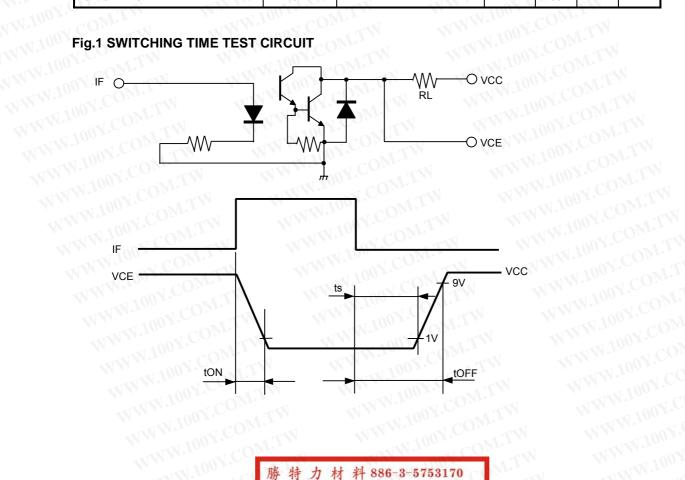
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SWITCHING CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNI
Rise Time	tr	V 10V	-0 4 1.1	40	_	
Fall Time	tf	— V _{cc} =10V — I _c =10mA		15	_	
Turn-on Time	ton	$- R_{L} = 100\Omega$		50	_	μs
Turn-off Time	toff		N.CO.	15	_	
Turn-on Time	tON		W.CO	5	N —	
Strage Time	ts	$R_{L}=180\Omega$ (Fig.1)	J.V.	40	<u> </u>	
Turn-off Time	tOFF	— V _{CC} =10V , I _F =16mA	100-21	80		

Fig.1 SWITCHING TIME TEST CIRCUIT



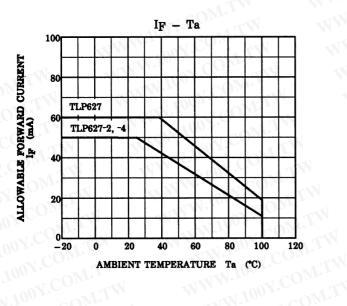
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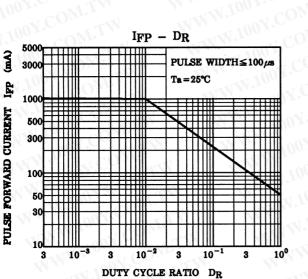
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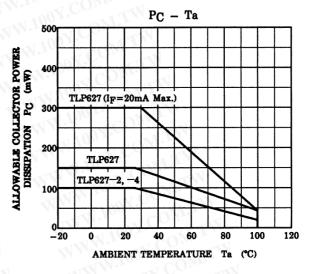
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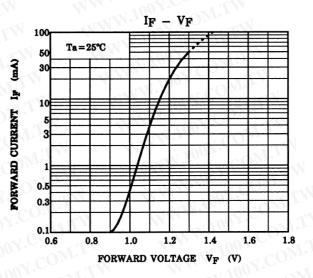
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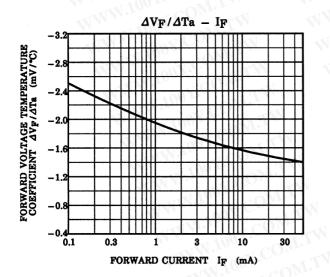
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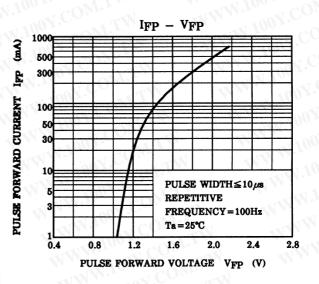






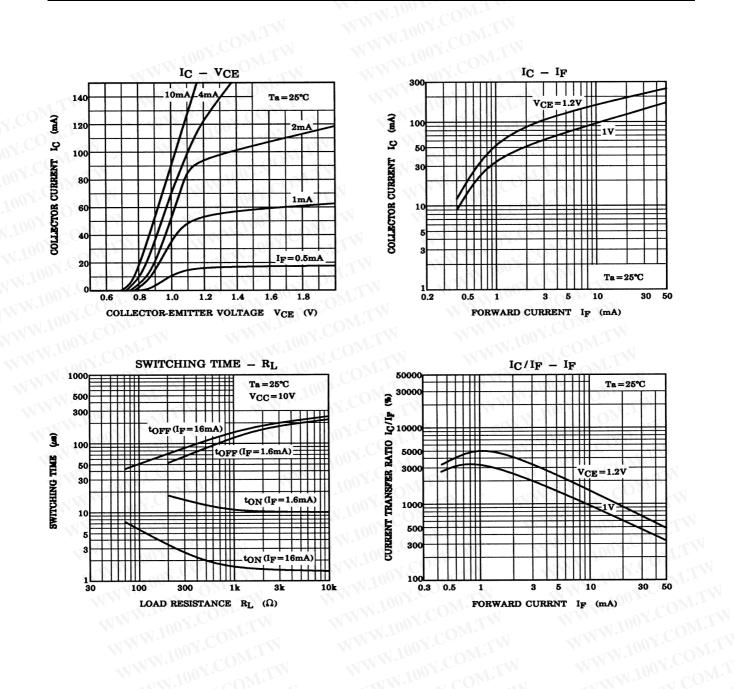


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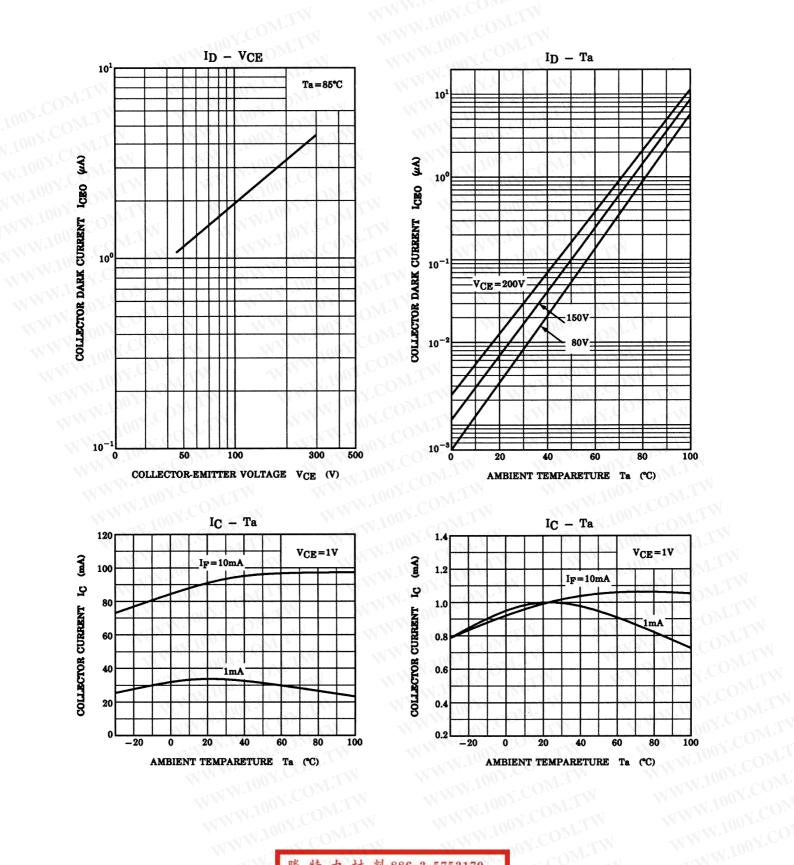
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